VSMY98545DS



Vishay Semiconductors

High Power Infrared Emitting Diode, 850 nm, Surface Emitter Technology



DESCRIPTION

As part of the <u>SurfLightTM</u> portfolio, the VSMY98545DS is an infrared, 850 nm emitting diode based on surface emitter technology with high radiant power and high speed, molded in low thermal resistance SMD package with lens. A 42 mil chip provides outstanding radiant intensity and allows DC operation of the device up to 1 A. Superior ESD characteristics are ensured by an integrated Zener diode.

FEATURES

- Package type: surface mount
- Double stack technology
- Package form: high power SMD with lens
- Dimensions (L x W x H in mm): 3.85 x 3.85 x 2.24
- Peak wavelength: $\lambda_p = 850 \text{ nm}$
- Zener diode for ESD protection up to 2 kV
- High radiant power
- High radiant intensity
- Angle of half intensity: $\phi = \pm 45^{\circ}$
- Designed for high drive currents: up to 1 A (DC) and up to 5 A pulses
- Low thermal resistance: R_{thJP} = 10 K/W
- Floor life: 168 h, MSL 3, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Infrared illumination for CMOS cameras (CCTV)
- Illumination for cameras (3D gaming)
- Machine vision
- 3D TV

PRODUCT SUMMARY

| COMPONENT | l _e (mW/sr) | φ (deg) | λ _p (nm) | t _r (ns) | |
|-------------|------------------------|---------|---------------------|---------------------|--|
| VSMY98545DS | 600 | ± 45 | 850 | 30 | |

Note

Test conditions see table "Basic Characteristics"

| ORDERING INFORMATI | ON | | |
|--------------------|---------------|----------------------------|----------------------|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM |
| VSMY98545DS | Tape and reel | MOQ: 600 pcs, 600 pcs/reel | High power with lens |

Note

• MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|--|----------------------------------|-------------------|-------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Reverse voltage | | V _R | 5 | V | |
| Forward current | | I _F | 1 | А | |
| Peak forward current | $t_p/T = 0.5, t_p = 100 \ \mu s$ | I _{FM} | 2 | А | |
| Surge forward current | t _p = 100 μs | I _{FSM} | 5 | А | |
| Power dissipation | | Pv | 3.6 | W | |
| Junction temperature | | Тj | 125 | °C | |
| Operating temperature range | | T _{amb} | -40 to +110 | °C | |
| Storage temperature range | | T _{stg} | -40 to +125 | °C | |
| Soldering temperature | Acc. figure 10, J-STD-20 | T _{sd} | 260 | °C | |
| Thermal resistance junction/pin | Acc. J-STD-051, soldered on PCB | R _{thJP} | 10 | K/W | |

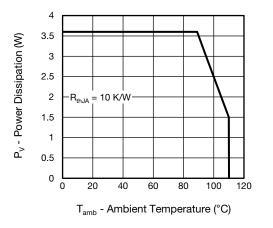
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COMPLIANT HALOGEN

GREEN (5-2008)





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Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

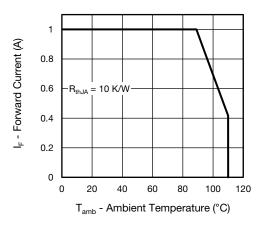


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---|---|------------------|------|------|------|-------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Ferrier duration of | I _F = 1 A, t _p = 20 ms | V _F | | 3.2 | 3.6 | V |
| Forward voltage | I _F = 5 A, t _p = 100 μs | V _F | | 4.6 | | V |
| Temperature coefficient of V_F | I _F = 1 A | TK _{VF} | | -2.2 | | mV/K |
| Reverse current | V _R = 5 V | I _R | | | 10 | μA |
| De die staiste se it. | I _F = 1 A, t _p = 20 ms | l _e | 300 | 600 | 900 | mW/sr |
| Radiant intensity | I _F = 5 A, t _p = 100 μs | l _e | | 2800 | | mW/sr |
| Radiant power | I _F = 1 A, t _p = 20 ms | фе | | 1070 | | mW |
| Temperature coefficient of ϕ_{e} | I _F = 1 A | TKφ _e | | | | %/K |
| Angle of half intensity | | φ | | ± 45 | | deg |
| Peak wavelength | I _F = 1 A | λρ | 830 | 850 | 870 | nm |
| Spectral bandwidth | I _F = 1 A | Δλ | | 50 | | nm |
| Temperature coefficient of λ_p | I _F = 1 A | ΤΚλ _p | | 0.3 | | nm/K |
| Rise time | I _F = 1 A | t _r | | 30 | | ns |
| Fall time | I _F = 1 A | t _f | | 30 | | ns |

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

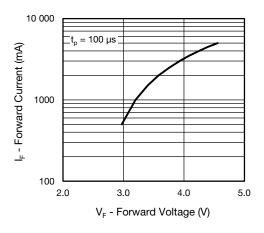


Fig. 3 - Forward Current vs. Forward Voltage

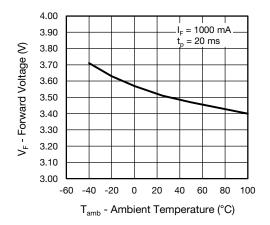


Fig. 4 - Forward Voltage vs. Ambient Temperature

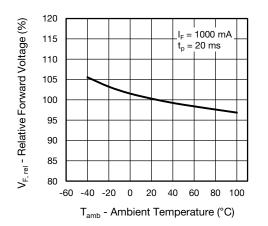


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

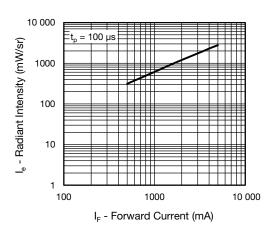


Fig. 6 - Radiant Intensity vs. Forward Current

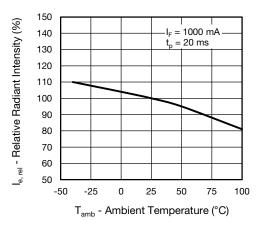


Fig. 7 - Relative Radiant Intensity vs. Ambient Temperature

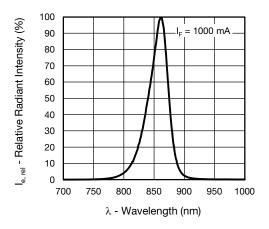


Fig. 8 - Relative Radiant Intensity vs. Wavelength

3 For technical questions, contact: <u>emittertechsupport@vishay.com</u>

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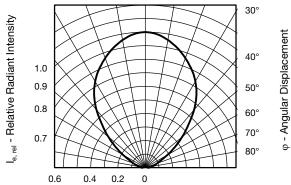
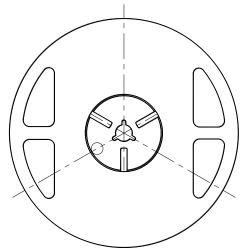
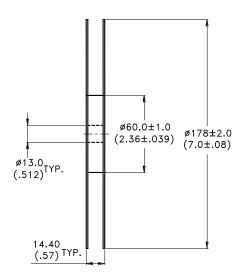


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

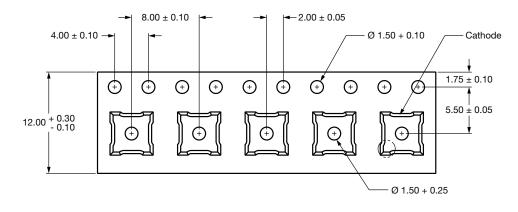
TAPING DIMENSIONS in millimeters





Notes

- Empty component pockets sealed with top cover tape.
- 7 inch reel 600 pieces per reel.
- The maximum number of consecutive missing lamps is two.
- In accordance with ANSI/EIA 481-1-A-1994 specifications.

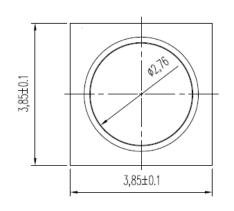


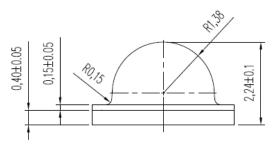
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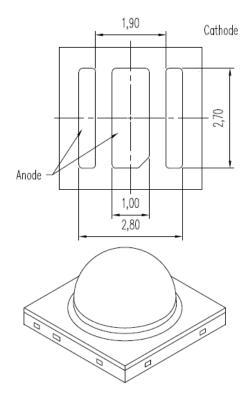
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PACKAGE DIMENSIONS in millimeters

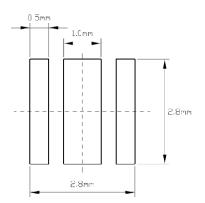




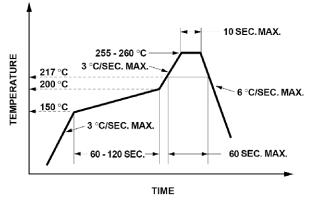


Notes

- Tolerance is \pm 0.10 mm (0.004") unless otherwise noted.
- Specifications are subject to change without notice.



SOLDER PROFILE



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Fig. 10 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 3, acc. to J-STD-020B

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.



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